

**CE**

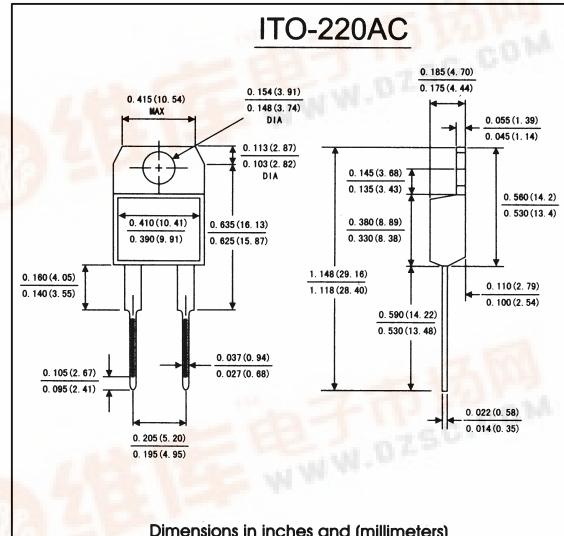
CHENYI ELECTRONICS

**SRF1020 THRU SRF1620(SINGLE CHIP)****SCHOTTKY BARRIER RECTIFIER****Reverse Voltage - 20 to 60 Volts****Forward Current - 10.0Amperes****FEATURES**

- . Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- . Metal silicon junction ,majority carrier conduction
- . Guard ring for overvoltage protection
- . Low power loss,high efficiency
- . High current capability ,Low forward voltage drop
- . Single rectifier construction
- . High surge capability
- . For use in low voltage ,high frequency inverters, free wheeling , and polarity protection applications
- . High temperature soldering guaranteed: 250°C/10 seconds
- 0.25"(6.35mm)from case

**MECHANICAL DATA**

- Case:** JEDEC DO-220AC molded plastic body
- Terminals:** lead solderable per MIL-STD-750,method 2026
- Polarity:** As marked
- Mounting Position:** Any
- Weight:** 0.08 ounce, 1.81 grams



Dimensions in inches and (millimeters)

**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

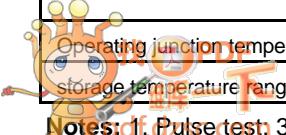
(Ratings at 25°C ambient temperature unless otherwise specified,Single phase,half wave,resistive or inductive)

load. For capacitive load,derate by 20%)

	Symbols	SRF1020	SRF1030	SRF1040	SRF1050	SRF1060	Units
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	20	30	40	50	60	Volts
Maximum RMS voltage	V <sub>RMS</sub>	14	21	28	35	42	Volts
Maximum DC blocking voltage	V <sub>DC</sub>	20	30	40	50	60	Volts
Macimum average forward rectified current(see Fig.1)	I <sub>(AV)</sub>			10.0			Amps
Repetitive peak forward current(square wavr, 20KHz) at T <sub>c</sub> =105°C	I <sub>FRM</sub>			20.0			Amps
Peak forward surge current 8.3ms singel half sine-wave superimposed on rated load (JEDEC method)	I <sub>FSM</sub>			150.0			Amps
Maximum instantaneous forward voltage at 10 A(Note 1)	V <sub>F</sub>		0.70		0.80		Volts
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	I <sub>R</sub>			1.0			mA
TA=25°C TA=125°C				30			
Typeical thermal resistance(Note 2)	R <sub>θ</sub> <sub>JC</sub>			5.0			°C/W
Operating junction temperature range	T <sub>J</sub>			-65 to +150			°C
storage temperature range	T <sub>STG</sub>			-65 to +150			°C

Notes: 1. Pulse test: 300 μ s pulse width,1% duty cycle

2. Thermal resistance from juntion to case



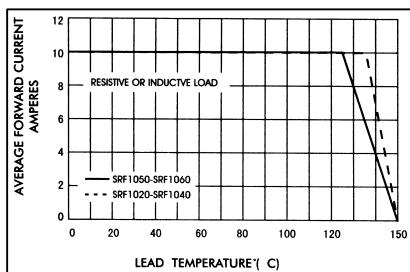
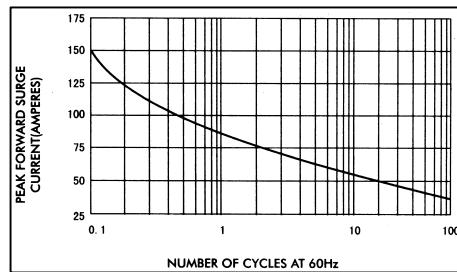
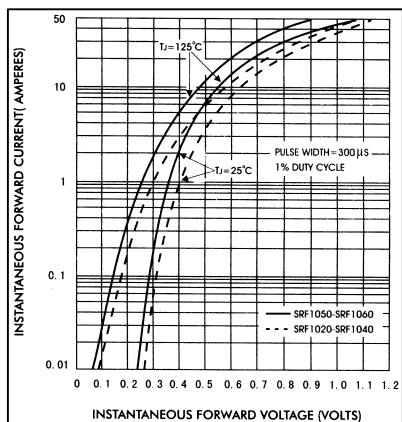
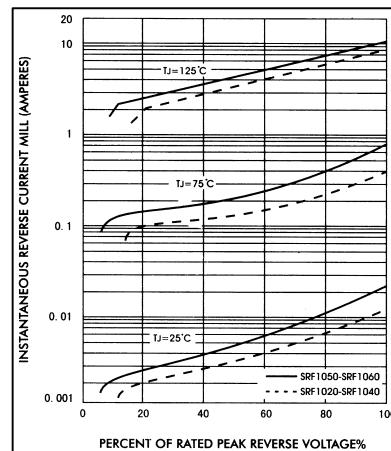
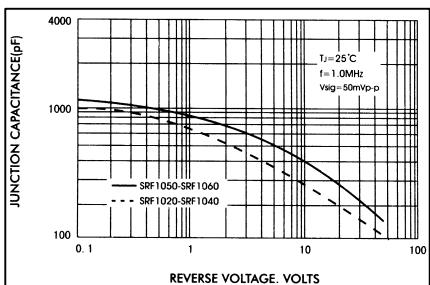
**CE**

CHENYI ELECTRONICS

**SRF1020 THRU SRF1620(SINGLE CHIP)****SCHOTTKY BARRIER RECTIFIER**

Reverse Voltage - 20 to 60 Volts

Forward Current - 10.0Amperes

**RATINGS AND CHARACTERISTIC CURVES SRF1020 THRU SRF1620****FIG.1-FORWARD CURRENT DERATING CURVE****FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT****FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS****FIG.4-TYPICAL REVERSE CHARACTERISTICS****FIG.5-TYPICAL JUNCTION CAPACITANCE****FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE**